

N-Channel Enhancement Mode Field Effect Transistor

FEATURES

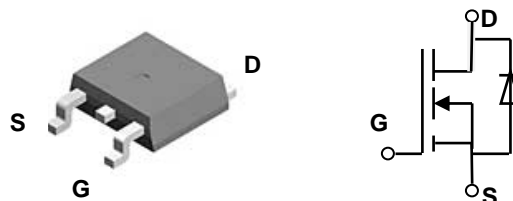
- Super high dense cell design for low $R_{DS(ON)}$
- Rugged and reliable
- Simple drive requirement
- TO-252 package

PRODUCT SUMMARY

| V_{DSS} | I_D | $R_{DS(ON)}$ (m Ω) Typ |
|-----------|-------|--------------------------------|
| 25V | 15A | 55 @ $V_{GS}=4.5V$ |
| | | 60 @ $V_{GS}=2.5V$ |



NOTE: The MT3055L is available in a lead-free package



ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|--|----------------|------------|------------|
| Drain-Source Voltage | V_{DS} | 25 | V |
| Gate-Source Voltage | V_{GS} | ± 12 | V |
| Drain Current-Continuous ^a @ $T_j=125^\circ C$ - Pulse d^b | I_D | 15 | A |
| | I_{DM} | 48 | A |
| Drain-source Diode Forward Current ^a | I_S | 1.7 | A |
| Maximum Power Dissipation ^a | P_D | 55 | W |
| Operating Junction and Storage Temperature Range | T_j, T_{STG} | -55 to 150 | $^\circ C$ |

THERMAL CHARACTERISTICS

| | | | |
|--|-------------|----|--------------|
| Thermal Resistance, Junction-to Ambient ^a | $R_{th JA}$ | 50 | $^\circ C/W$ |
|--|-------------|----|--------------|

ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise noted)

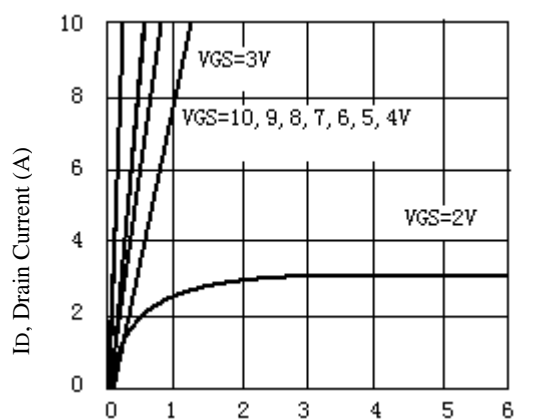
| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|----------------------------------|---------------------|--|-----|------|------|------|
| OFF CHARACTERISTICS | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V,I _D =250μA | 25 | | | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =16V,V _{GS} =0V | | | 1 | μA |
| Gate-Body Leakage | I _{GSS} | V _{GS} =±8V,V _{DS} =0V | | | ±100 | nA |
| ON CHARACTERITICS | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} ,I _D =250μA | 0.8 | 1.1 | 2.0 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =4.5V,I _D =2.8A | | 50 | 65 | m Ω |
| | | V _{GS} =2.5V,I _D =2.0A | | 60 | 85 | |
| Forward Transconductance | g _{FS} | V _{GS} =7V,I _D =5A | | 5 | | S |
| DAYNAMIC CHARACTERISTICS | | | | | | |
| Input Capacitance | C _{ISS} | V _{DS} =10V,V _{GS} =0V f=1.0MHz | | 608 | | pF |
| Output Capacitance | C _{OSS} | | | 101 | | pF |
| Reverse Transfer Capacitance | C _{RSS} | | | 59 | | pF |
| SWITCHING CHARACTERISISTICS | | | | | | |
| Turn-On Delay Time | t _{D(ON)} | V _{DD} =10V I _D =15A, V _{GEN} =4.5V R _L =10ohm R _{GEN} =10ohm | | 6.5 | | ns |
| Rise Time | t _r | | | 32.1 | | ns |
| Turn-Off Delay Time | t _{D(OFF)} | | | 58.4 | | ns |
| Fall Time | t _f | | | 48 | | ns |
| Total Gate Charge | Q _g | V _{DS} =10V,I _D =1A V _{GS} =4.5V | | 6 | | nC |
| Gate-Source Charge | Q _{gs} | | | 1.35 | | nC |
| Gate-Drain Charge | Q _{gd} | | | 1.5 | | nC |

ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

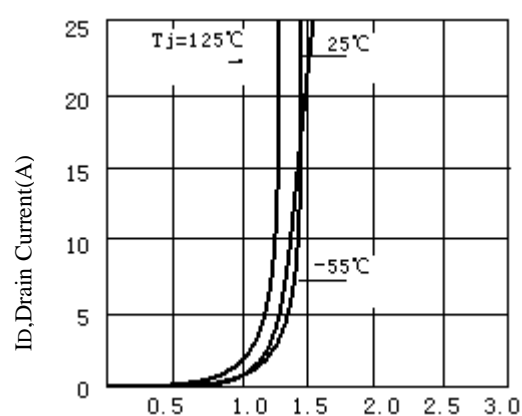
| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|------------------------------------|-----------------|--|-----|------|-----|------|
| DRAIN-SOURCE DIODE CHARACTERISTICS | | | | | | |
| Diode Forward Voltage | V _{SD} | V _{GS} =0V, I _S =1.25A | | 0.84 | 1.2 | V |

Notes

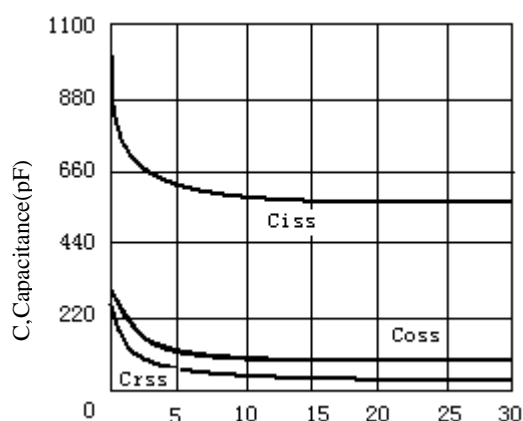
- Surface Mounted on FR4 Board, t ≤ 10sec
- Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%
- Guaranteed by design, not subject to production testing.



V_{DS}, Drain-to-Source Voltage (V)
Figure 1. Output Characteristics



V_{GS}, Gate-to-source Voltage (V)
Figure 2. Transfer Characteristics



V_{GS}, Drain-to Source Voltage
Figure 3. Capacitance

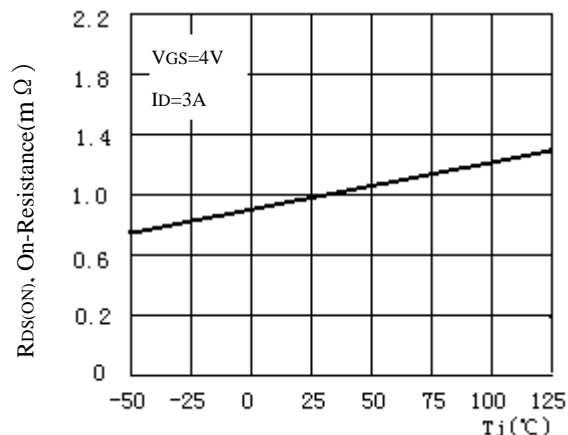
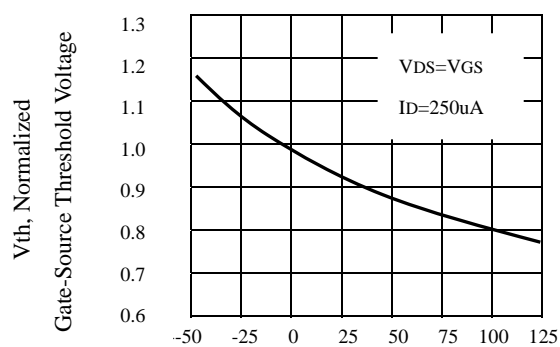
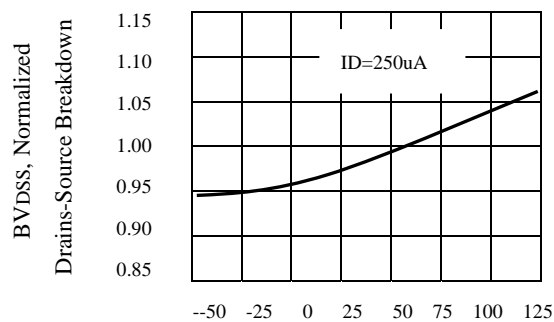


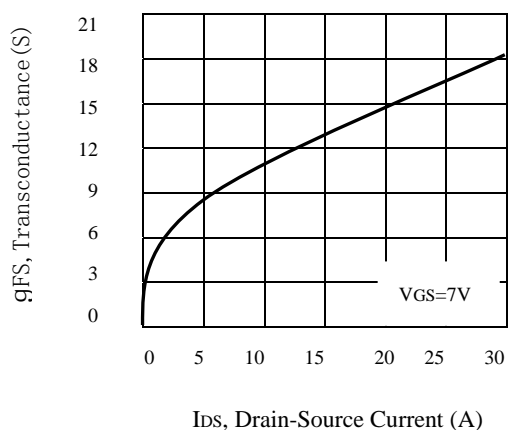
Figure 4. On-Resistance Variation with Temperature



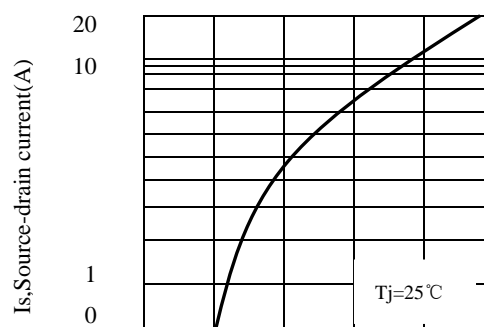
Tj, Junction Temperature (°C)
Figure 5. Gate Threshold Variation
With Temperature



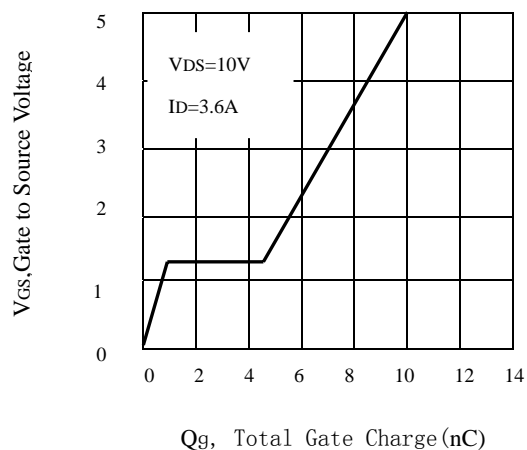
Tj, Junction Temperature (°C)
Figure 6. Breakdown Voltage Variation
With Temperature



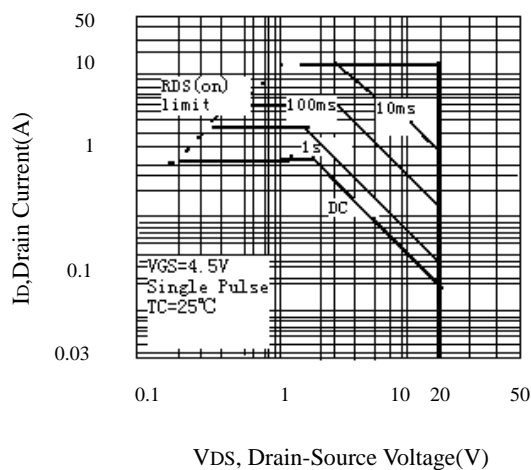
IDS, Drain-Source Current (A)
Figure 7. Transconductance Variation
With Drain Current



VSD, Body Diode Forward Voltage
Figure 8. Body Diode Forward Voltage
Variation with Source Current



Qg, Total Gate Charge (nC)
Figure 9. Gate Charge



VDS, Drain-Source Voltage (V)
Figure 10. Maximum Safe Operating Area



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